

64 k EEPROM (8-kword x 8-bit) Ready/Busy function, RES function (HN58V66A)

Manufacturers	Renesas Technology Corp
Package/Case	SOP28
Product Type	Programmable Logic ICs
RoHS	
Lifecycle	



Images are for reference only

Please submit RFQ for HN58V65AFP-10 or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

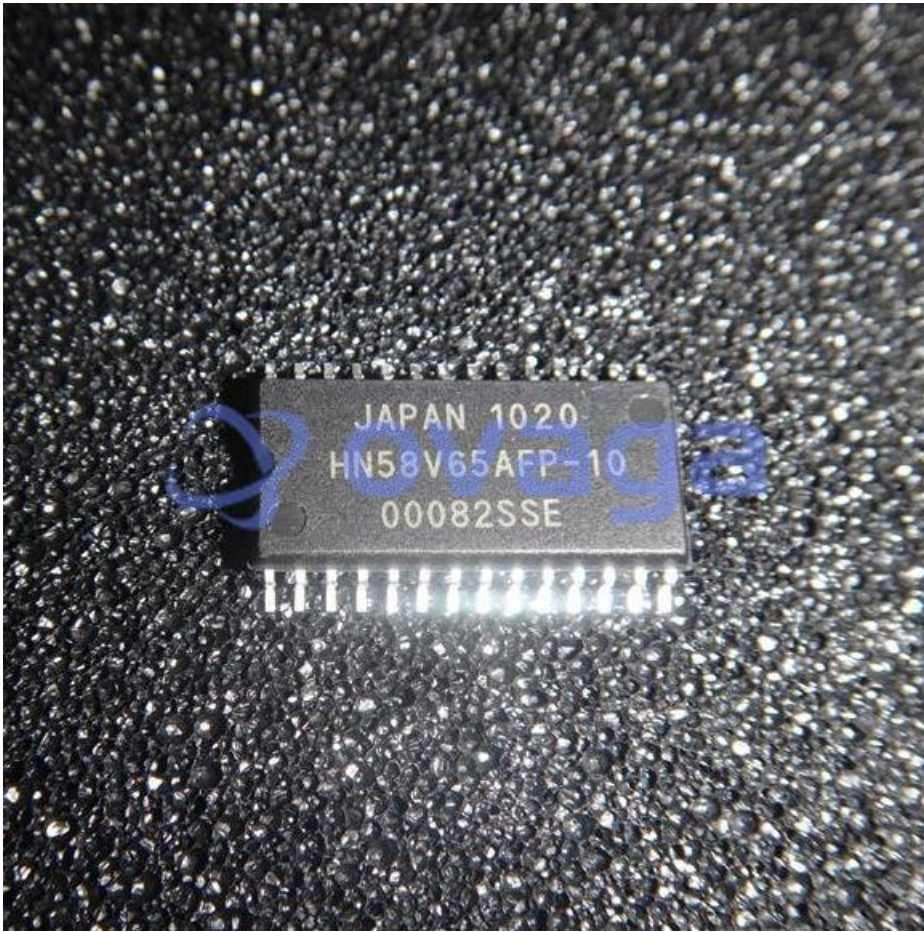
HN58V65AFP-10 is a specific model of non-volatile SRAM (NVS RAM) manufactured by Renesas Electronics Corporation. Here are some of its features:

Features

- Capacity: 64Kbit
- Operating voltage: 4.5V to 5.5V
- Access time: 70ns
- Low power consumption
- Non-volatile data retention with fast store-to-memory capability

Application

- Cypress Semiconductor Corporation CY14B101PA-SFXI
- Integrated Silicon Solution, Inc. IS61C256AH-15JLI
- Microchip Technology Inc. 23LC1024-I/SN
- ON Semiconductor CAT25C64LI-G



Related Products



[HD64F2378BVFQ35V](#)

Renesas Technology Corp
QFP144



[HD64F2138AFA20V](#)

Renesas Technology Corp
QFP80



[HD6417709SHF200BV](#)

Renesas Technology Corp
QFP



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[HD6412352F20V](#)

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[HD6417750F167V](#)

Renesas Technology Corp
208-BFQFP Exposed Pad



[HD64F3062BF25V](#)

Renesas Technology Corp
PQFP-100